

August 2008

QEC121, QEC122, QEC123 Plastic Infrared Light Emitting Diode

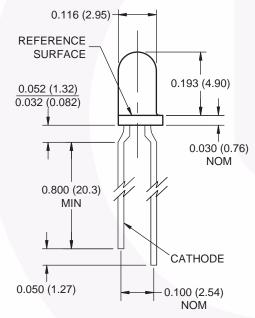
Features

- λ = 880nm
- Chip material = AlGaAs
- Package type: T-1 (3mm)
- Matched photosensor: QSC112/QSC113/QSC114
- Narrow emission angle, 8° at 80% intensity
- High output power
- Package material and color: clear, purple tinted, plastic

Description

The QEC121, QEC122 and QEC123 are 880nm AlGaAs LED encapsulated in a clear purple tinted, plastic T-1 package.

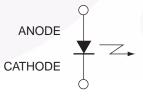
Package Dimensions







Schematic



Notes:

- 1. Dimensions of all drawings are in inches (mm).
- 2. Tolerance is ± 0.10 (0.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings (T_A = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating	Units
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) ⁽²⁾⁽³⁾⁽⁴⁾	240 for 5 sec	°C
T _{SOL-F}	Soldering Temperature (Flow) ⁽²⁾⁽³⁾	260 for 10 sec	°C
I _F	Continuous Forward Current	50	mA
V _R	Reverse Voltage	5	V
P _D	Power Dissipation ⁽¹⁾	100	mW

Notes:

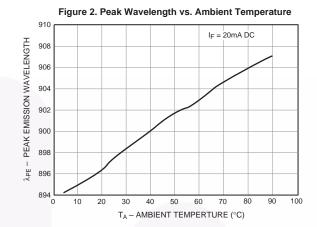
- 1. Derate power dissipation linearly 1.33mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.

Electrical / Optical Characteristics (T_A = 25°C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
λ_{PE}	Peak Emission Wavelength	I _F = 100mA		890		nm
TC_λ	Temperature Coefficient			0.2		nm/°C
2⊖ ¹ /2	Emission Angle	I _F = 100mA		18		0
V _F	Forward Voltage	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$			1.7	V
TC _{VF}	Temperature Coefficient			-6		mV/°C
I _R	Reverse Current	$V_R = 5V$			10	μA
Ι _Ε	Radiant Intensity QEC121	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$	14			mW/sr
Ι _Ε	Radiant Intensity QEC122	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$	27		94	mW/sr
IE	Radiant Intensity QEC123	$I_F = 100 \text{mA}, \text{ tp} = 20 \text{ms}$	39	45		mW/sr
TC _{IE}	Temperature Coefficient			-0.3		%/°C
t _r	Rise Time	I _F = 100mA		900		ns
t _f	Fall Time	1		800		ns
C _j	Junction Capacitance	$V_R = 0V$		11		pF

Typical Performance Curves

Figure 1. Normalized Intensity vs. Wavelength 1.0 0.9 0.8 NORMALIZED INTENSITY 0.7 0.6 0.5 0.4 0.3 0.2 0.1 750 800 850 900 950 1,000 1,050



Normalized to: IF = 100mA Pulsed tpW = 20mS Duty Cycle = 4% $T_A = 25^{\circ}C$

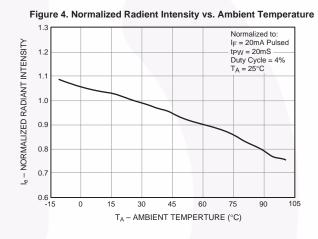
Ie - NORMALIZED RADIANT INTENSITY

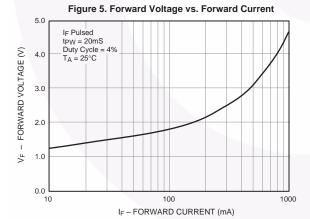
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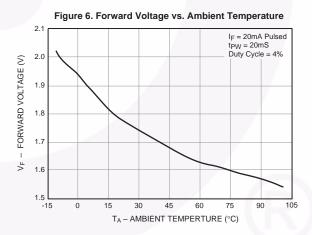
10

λ (nm)

Figure 3. Normalized Radiant Intensity vs. Forward Current 1000 I_F - FORWARD CURRENT (mA)

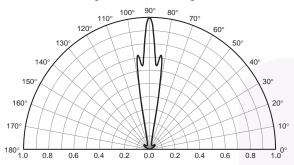


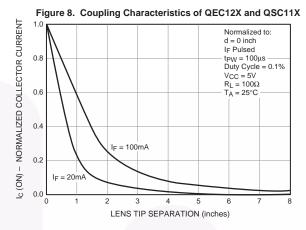




Typical Performance Curves (Continued)

Figure 7. Radiation Diagram









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Rev. I36